



MACOM Technology Solutions Holdings (MTSI)

March 2019



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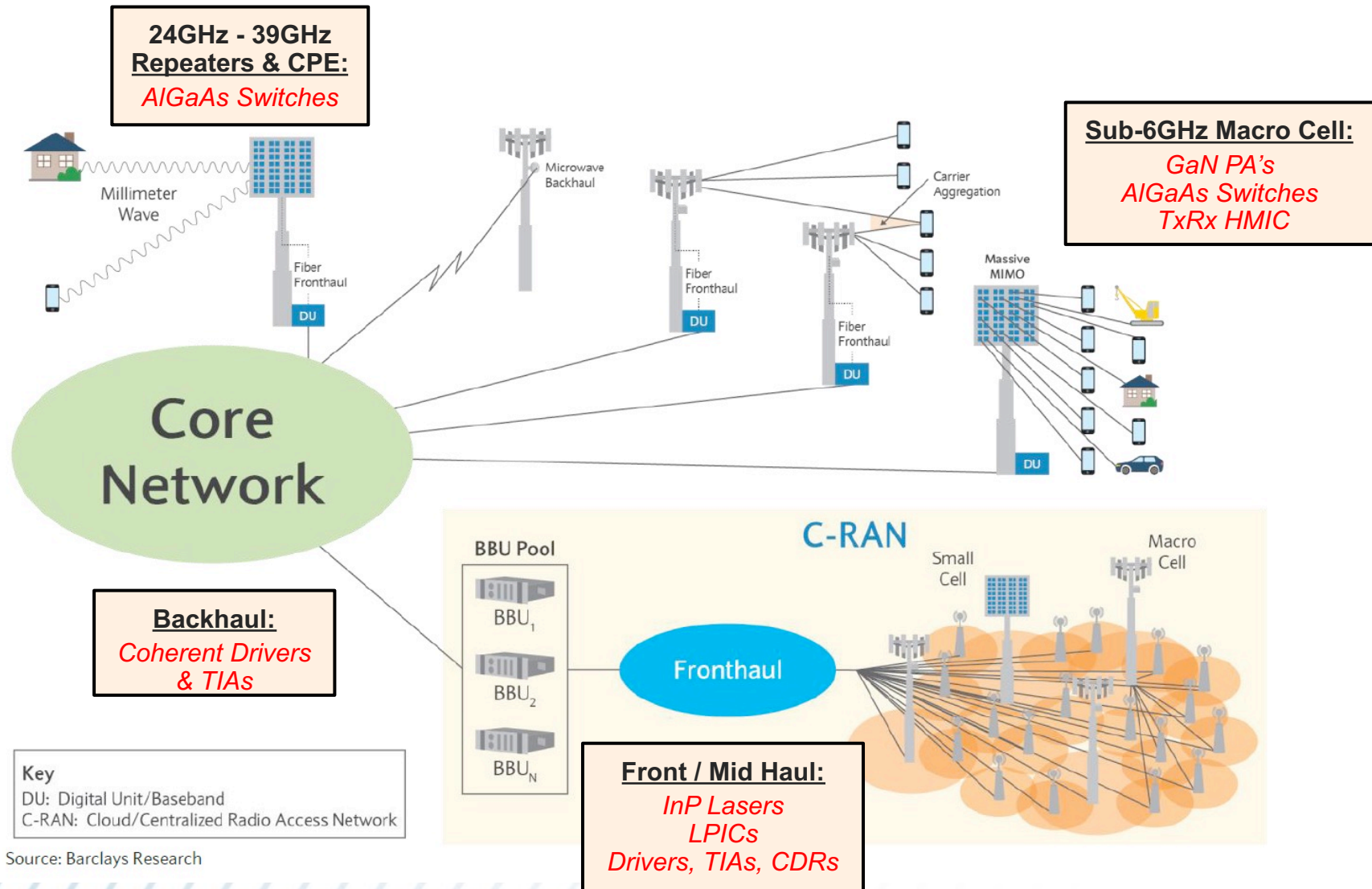
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5G—New Network Architecture

Massive MIMO Active Antenna Arrays, More Optical Links



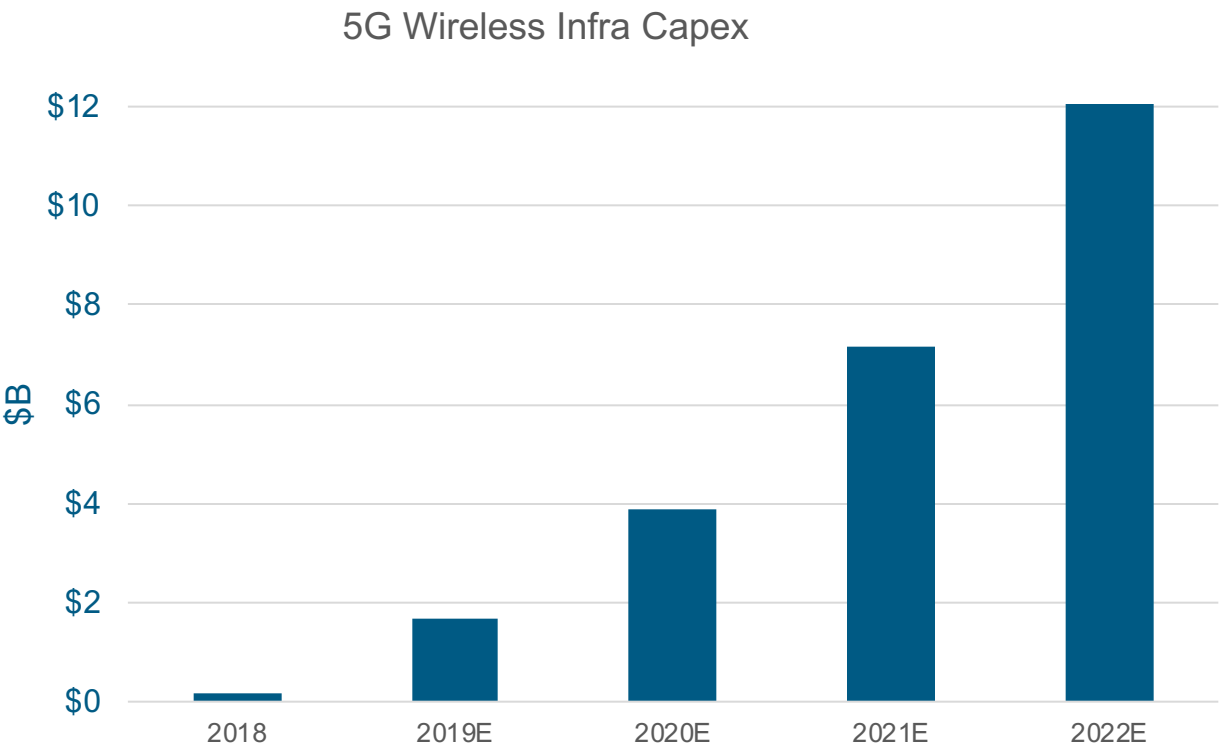
»» Deploying 5G antennas requires breakthroughs in energy efficiency, cost structures, quality of service and subscriber coverage

Critical challenges remain:

- > Quality of service goals constrained by **performance** of traditional microwave and millimeterwave technologies
- > **Form factor and thermal constraints** inhibit conventional beamforming architectures
- > **Cost structures** not yet affordable for mainstream deployments
- > **Energy consumption** does not meet operating expense targets and thermal constraints
- > **Supply chains** for key technologies not robust across the industry



5G Wireless Infrastructure Capex



Source: Dell'Oro, Mobile RA Five Year Forecast, July 2018

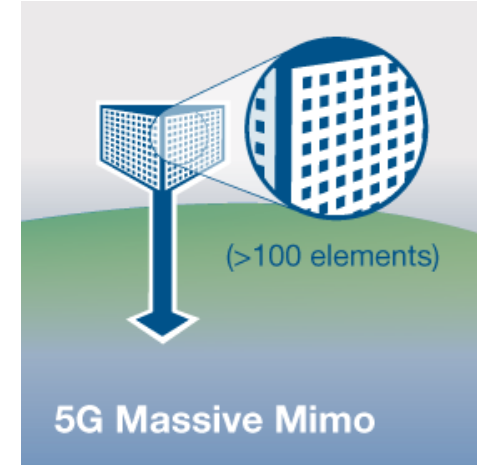
Sub-6GHz Growth Engine

Sub-6GHz Massive MIMO



4G Sector Antenna

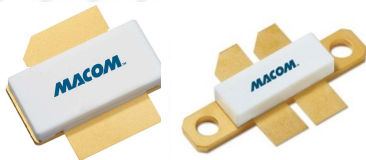
16-32x Increase in PA
Count per Sector



5G Massive MIMO

4G Macro BTS:

- > Up to 4x4 MIMO (4T4R)
- > $P_{\text{peak}} \sim 200\text{W} - 750\text{W}$
- > Freq: 700MHz–2.6GHz



Ceramic Package



Air Cavity Package

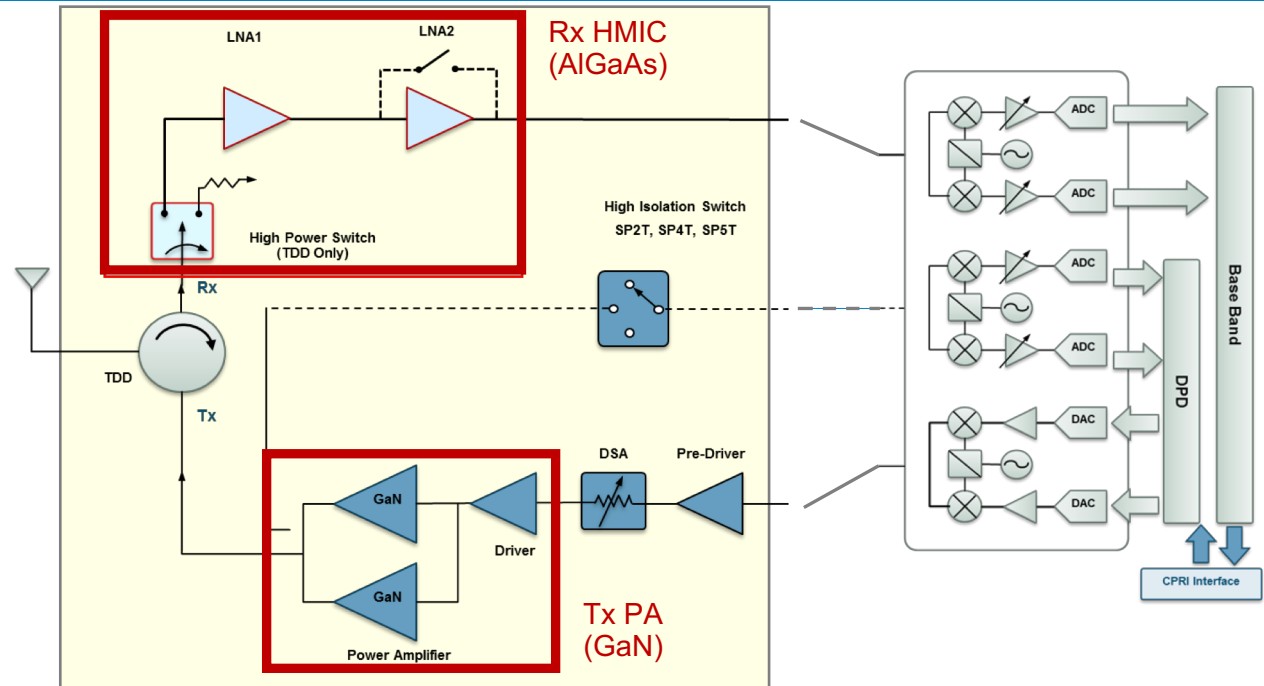
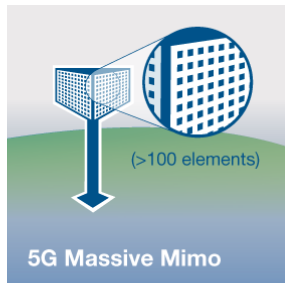
5G M-MIMO BTS:

- > 64 Element Array (64T64R)
- > $P_{\text{avg}} \sim 6\text{W} - 8\text{W}$ ($\sim 50\text{W}_{\text{peak}}$)
- > Freq: Sub-6GHz



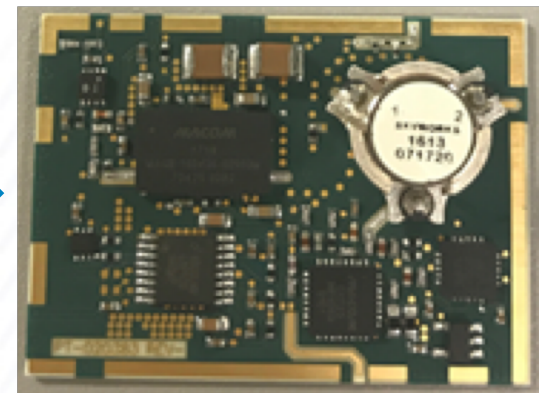
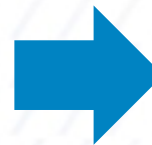
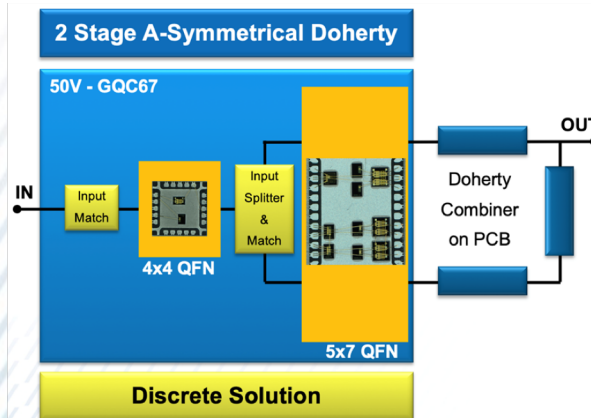
QFN Package

Sub-6GHz Massive MIMO



TxRx Element Detail

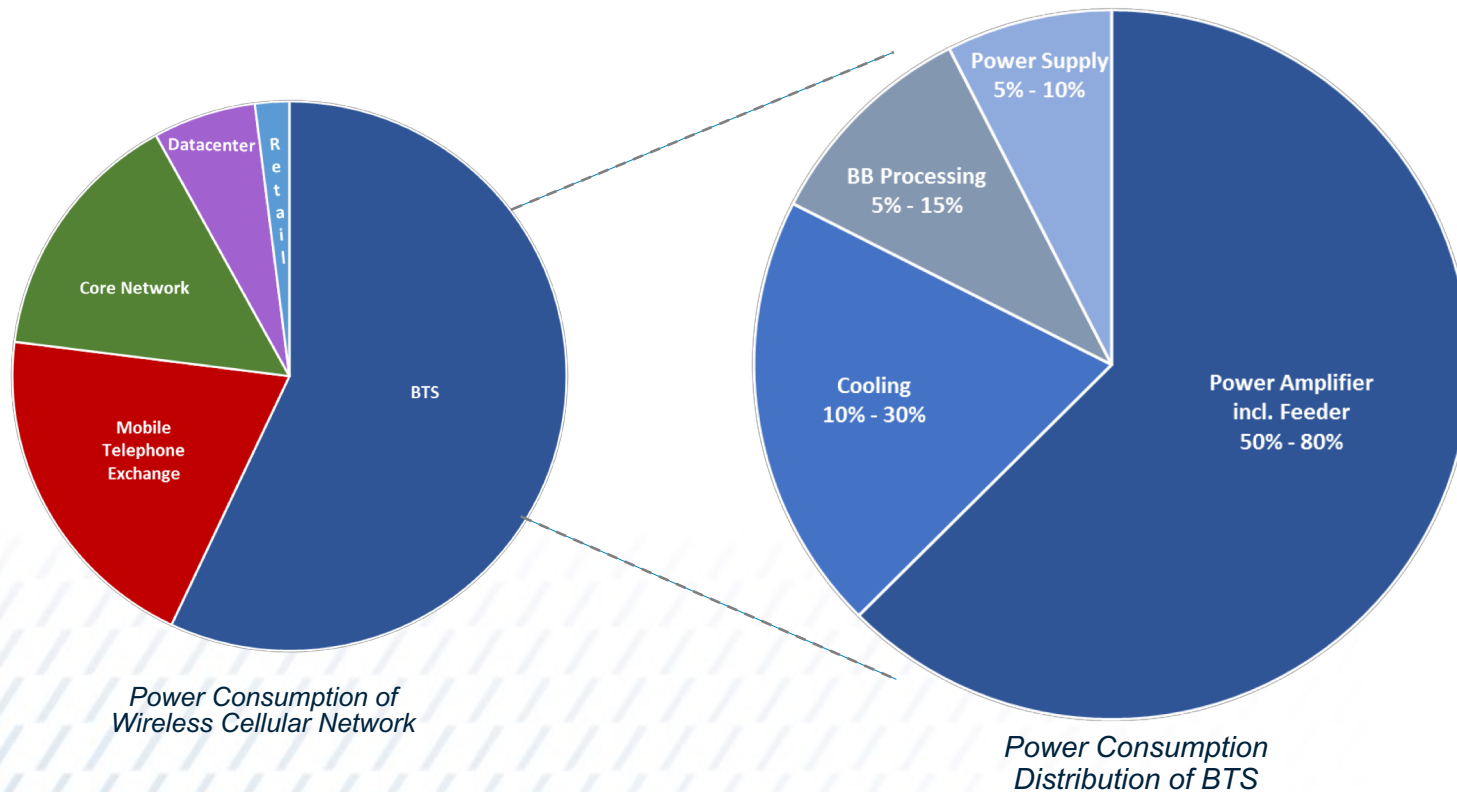
Single
Element
Complete
TR Module



GaN is a Requisite for 5G M-MIMO



Power Amplifiers Comprise up to 75% - 90% of Total BTS Power Consumption, Either Directly or Indirectly



GaN-on-Si Basestation Power Amplifiers



MACOM GaN Technology Fully Qualified and Deployed in the Field



MACOM
Partners from RF to Light

GaN-on-Silicon Reliability and Qualification Report

> A summary analysis of application-specific stress testing methodologies and results demonstrating the reliability of Gallium Nitride on Silicon (GaN-on-Si) RF power transistors for commercial wireless basestation infrastructure

INTRODUCTION

The performance and reliability benefits of GaN-on-Si for RF and microwave applications have been well documented since the 2006 qualification of first-generation GaN-on-Si technology for volume deployment into military and defense applications. With millions of GaN-on-Si RF transistors shipped to date, the multi-generation maturation of GaN-on-Si technology has opened the door to its mainstream commercial deployment in 4G LTE and 5G wireless basestation infrastructure, and onward to solid-state RF energy applications spanning cooking, lighting, automotive ignition and beyond.

The qualification methodologies employed for GaN-on-Si technology are similarly mature, informed by decades of industry standardized testing of silicon-based devices. The comprehensive testing data gathered on GaN-on-Si-based RF power transistors over multiple generations of GaN-on-Si fabrication shows a marked progression in key metrics centric to device performance and reliability.

MACOM GaN Generational Improvements

Attribute	Gen2	Gen3	Gen4
Year Qualified	2006	2013	2017
Operating Voltage	28V	50V	50V
Activation Energy	2.0eV	2.34eV	3.14eV
MTTF @125°C	165 hrs	300 hrs	400 hrs

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Partners from RF to Light

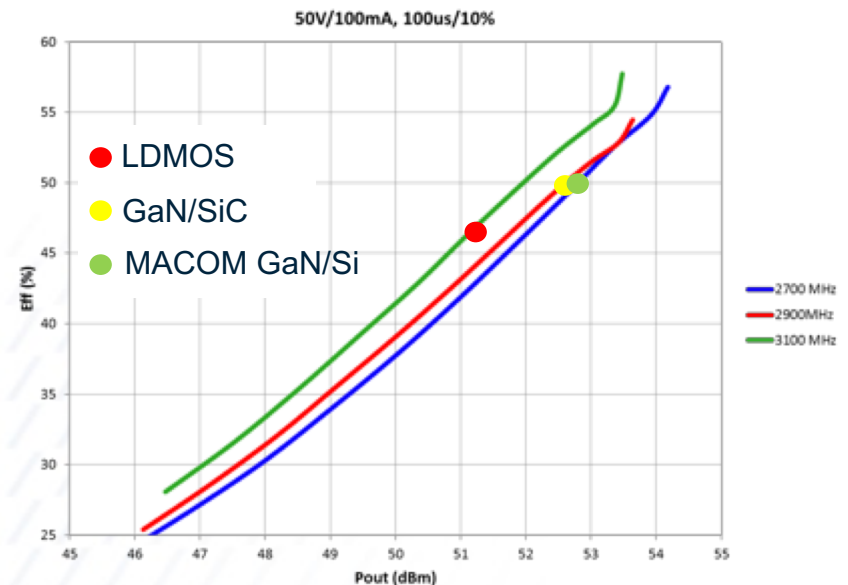
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MAGX-102731-180



AC-360B

- $V_{DS} = 50 \text{ V}$
- Freq. = 2700 – 3100 MHz
- $P_{OUT} = 180 \text{ W}$
- Pulse Conditions: 100 μs / 10%
- Power Gain > 14.5 dB
- Drain Efficiency > 50%



Over 1.5 Million GaN-on-Si Devices in the Field Today

MACOMTM



Customers

HARRIS

**Rockwell
Collins**

NOKIA

Products

Part Number	Ordering	Short Description	Frequency Range (GHz)	Supply Voltage (V)	PLAT (dB)	Gain (dB)	Test Freq (GHz)	Efficiency	Package
MACO-10000-000	Require	GaN-on-Si Power Transistor 100 W, 100 MHz		28	100	16	2.45	70	AC-10000-0-1-100-0
MACO-07000	Buy	GaN Wideband Transistor 20 W, 100 MHz - 6 GHz	0.1 - 6.0	28	6	9	5.8	+40	Power PHEM 2420
MACO-10000-0100P	Require			28	10	15.0		68	Lead-Free 100 W 100 MHz 100W Package
MACO-10000-000-000	Require	100 W GaN-on-Si Power Transistor 1.2 - 1.4 GHz	1.2 - 1.4 GHz	28	100	16		70	Conformal Surface Mount
MACO-10000-0100-000	Require	100 W 3-Stage Hybrid GaN-on-Si Module 2.0 - 2.4 GHz	2.0 - 2.4	28	10	22	2.4	40	MMT
MACO-00000-0100-000	Require	GaN Wideband Transistor 10 W, 100 MHz - 6 GHz	0.1 - 6.0	28	10	12	2.4	70	Die
MACO00000	Buy	GaN-on-Si Power Transistor 10 W, 100 MHz - 6 GHz	0.1 - 6.0	28	10	12	2.4	70	Power PHEM 2420
MACO000	Require	GaN Wideband Power Amplifier 20 W, 100 MHz	0.1 - 6.0	28	10.0	16	2.4	+40	Substrate Mount PHEM Package
MACO001	Require	GaN Wideband Power Amplifier 20 W, 100 MHz	0.1 - 6.0	28	10	16	2.4	+40	Substrate Mount PHEM
MACO000	Buy	GaN Wideband Power Amplifier 20 W, 100 MHz	0.1 - 6.0	28	10	16	2.4	+40	Substrate Mount PHEM

5G MMIC Comparison

MACOM GaN vs. GaN on SiC vs. LDMOS



	LDMOS	MACOM GaN	GaN on SiC	Benefits
2-stage Doherty PA Efficiency @3.6 GHz	43%	48%	48%	Lower Operating Expense
Higher Frequency Bands	2.7GHz & 3.8GHz	Up to and >6GHz	Up to and >6GHz	New Spectrum Deployments
Wider Bandwidths	100MHz	200MHz	200MHz	Higher Capacity per BTS
Power Density	1-1.5W/mm	4-8W/mm	4-8W/mm	Smaller Antenna, Lower CapEx
Linearity	DPD Friendly	DPD Friendly	Charge Trapping	Higher Modulation Schemes/Capacity
Supply Chain	8"	Up to 8"	4" → 6"	Operational Scale/ Surge Capability
Cost	Silicon Substrate	Silicon Substrate	SiC Substrate	LDMOS-like Cost Structure

MACOM & ST Investment in Industrialization



➤➤➤ RF Power Amplifier TAM Expected to Exceed \$3 Billion* by CY2022

Catania, Italy



Singapore

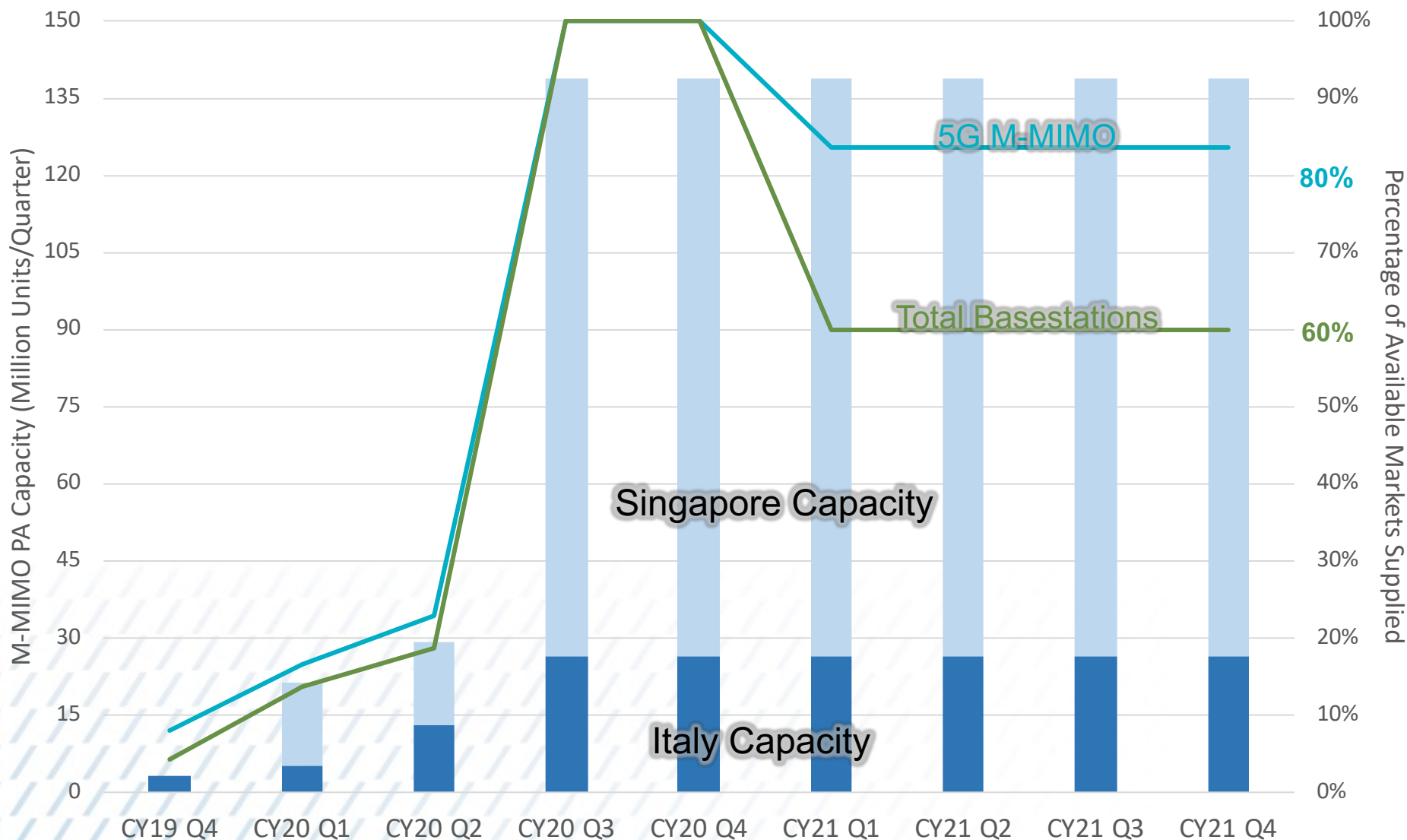


- Dual, independent sources in Europe and Asia
- Copy exact, 6"/8" (150/200mm) capacity
- $0.5\mu\text{m} > 0.25\mu\text{m} > 0.15\mu\text{m}$

Basestation PAs

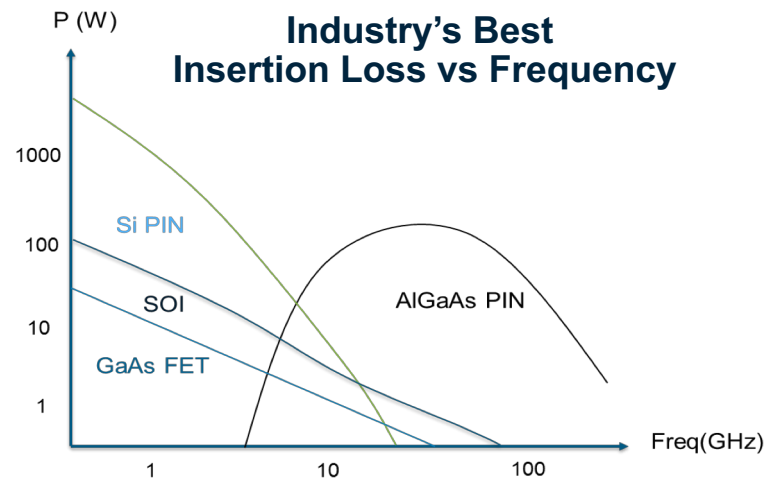


Estimated ST Enabled Capacity and Coverage of Available Market

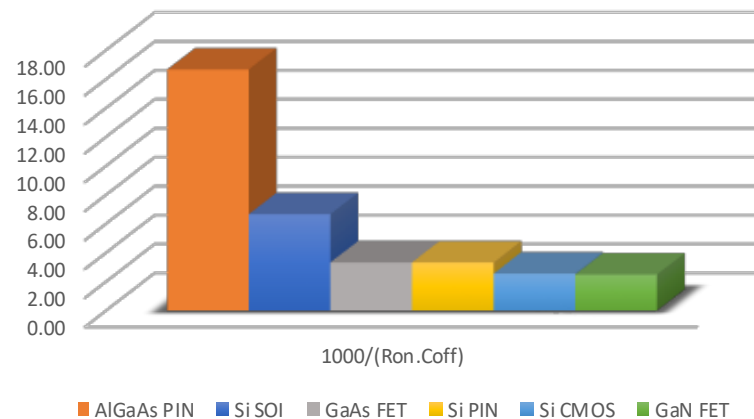


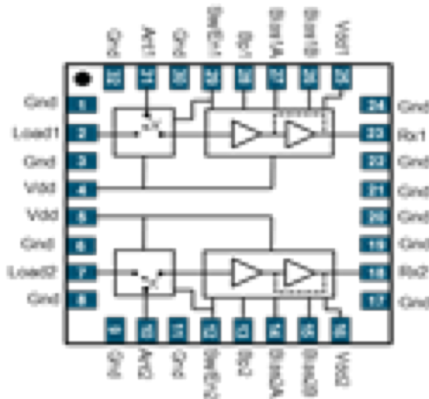
The AlGaAs Advantage

- Patented AlGaAs Discrete and MMIC Processes and Products
- Broad Portfolio of Millimeterwave PAs and LNA's to Offer Full System Solutions

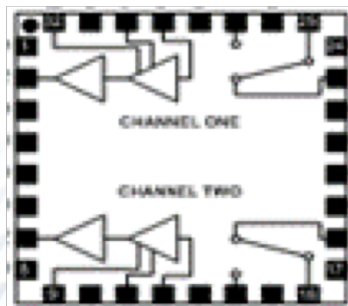


Process Figure of Merit





**Dual SW+LNA
Module**



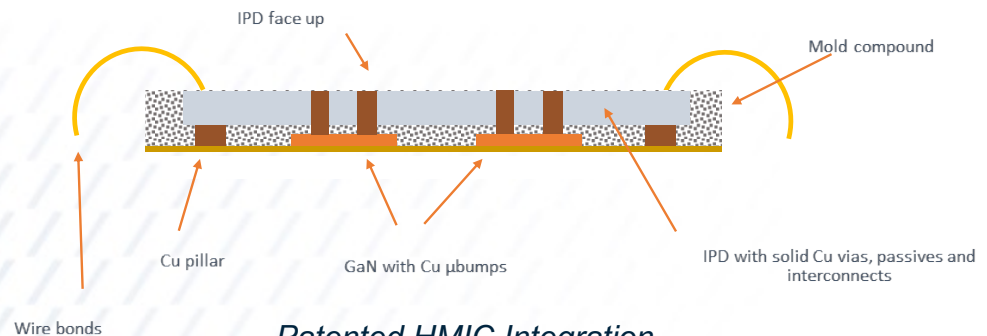
**Dual SW+LNA
with Bias and
Matching**

> Rx HMIC

- GaAs LNA
- AlGaAs T/R Switches
- SOI Switches and Control Components

> TRx HMIC

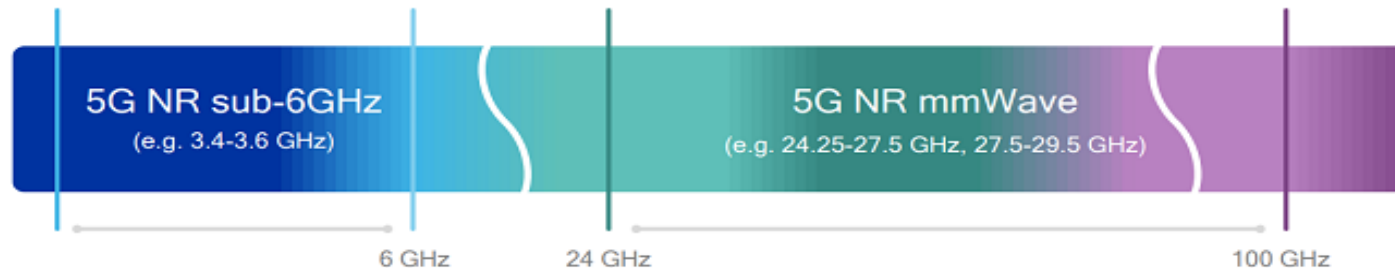
- GaN PA, GaAs LNA, Switch, PMIC, Coupler, Circulator



Patented HMIC Integration

5G Millimeterwave Growth Engine

»» To Support 5G Across All Frequencies and Power Levels and Geographies – Cost, Performance, Integration and Technology



> “Macro” Power Levels: 100’s Watt

- Frequency 600 MHz → 5 GHz
- Traditional “Basestation” model of discrete transistor based power
- Additional Bands at 3.5 and 4.9 GHz → drives GaN solutions

> Integrated Solutions – Power Levels <10 Watt

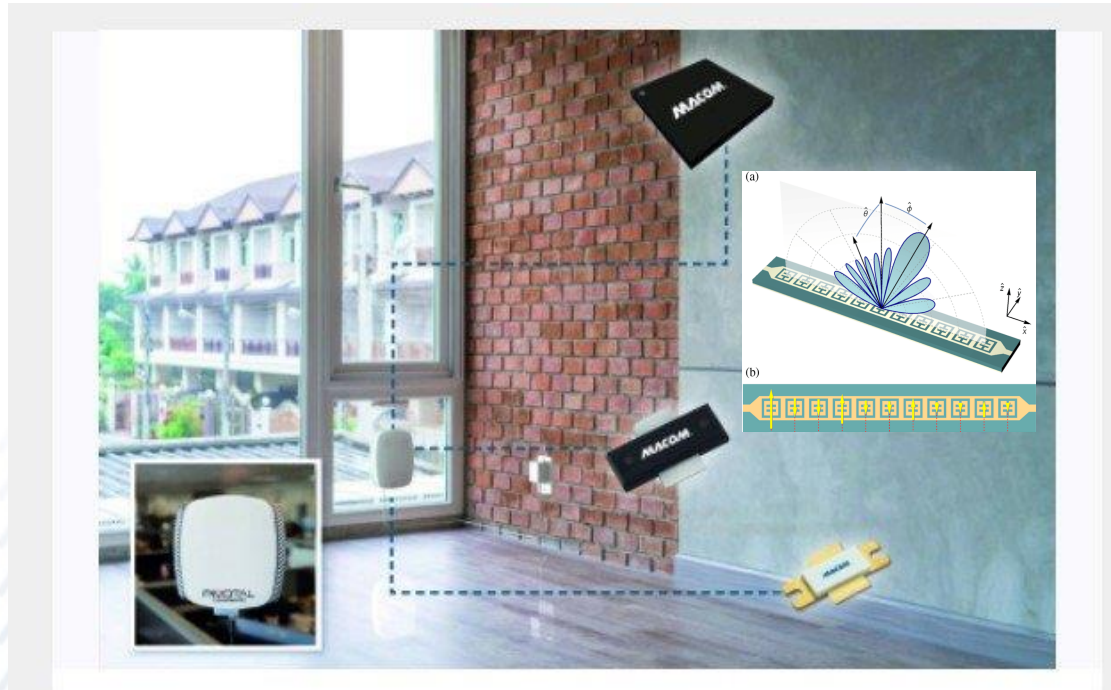
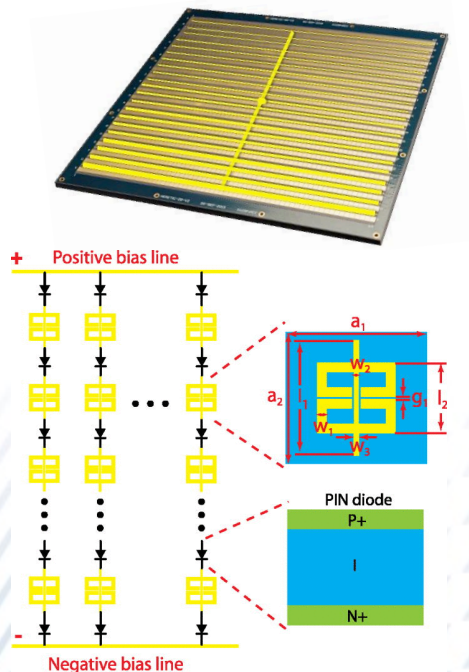
- Requires GaN MMIC products
- Integration key for performance and cost

> 5G mmWave Challenges

- Multiple Approaches
- Requires Beamforming
- Common Issues: Cost, Component Size, Thermal Management, Architecture
- Multiple Frequency Bands: 24 GHz → 39GHz → ??

Metamaterial Array Antennas

- Uses an Array of 600-1000 MACOM GaAs and AlGaAs Components
- *Holographic Beam Forming®* Antenna Topology
- Lowest C-SWaP Compared to Conventional Millimeterwave Beamforming



Echo 5G Network Infrastructure

